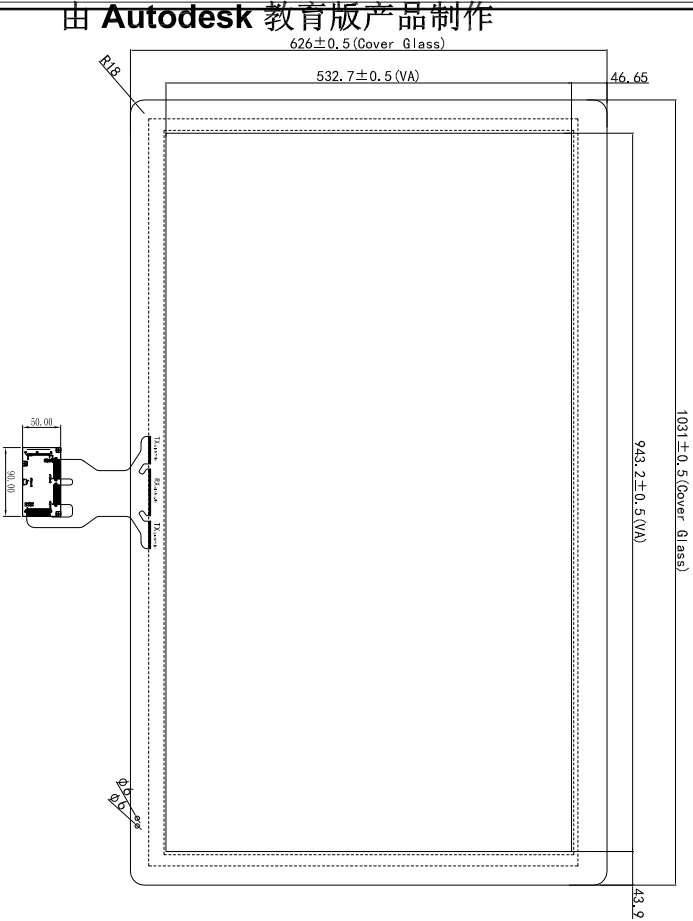


REV	MARK	HISTORY	DATE	NAME
REV.0	—		2017.01.12	ZH
REV.1	—	更改为ILITEK方案	2019.01.17	ZH

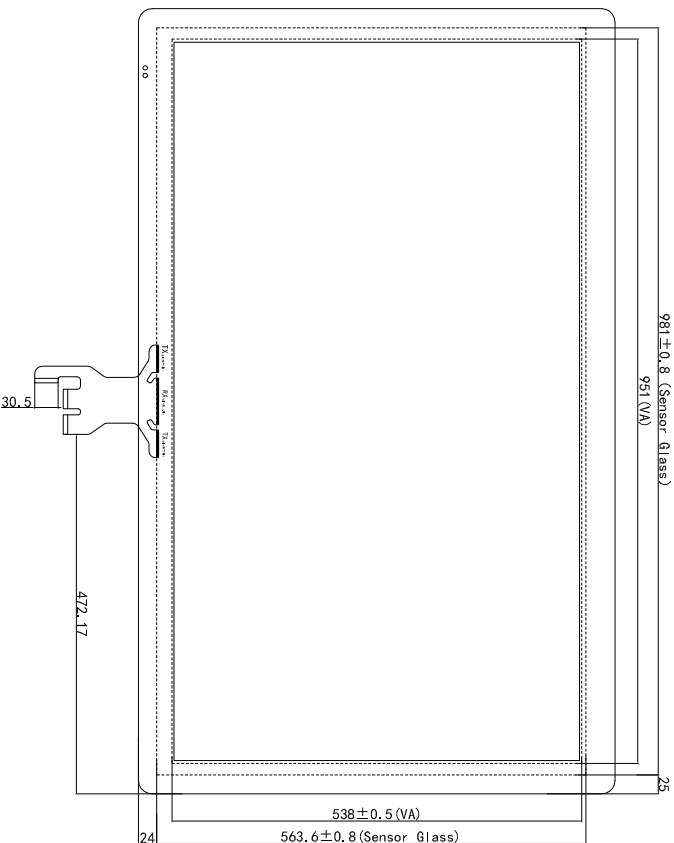
正视图



侧视图



背视图



Notes:

1. TP Structure: G+G;
2. TP Type: COB; IC: ILITEK 2315
3. Transmittance: ≥85%
4. Hardless: >6H
5. Operating conditions: -10°C~+60°C, ≤85%RH
6. Storage conditions: -10°C~+65°C, ≤85%RH
7. Unspecified tolerance: ±0.2mm
8. All materials in the drawing comply with the Rosh

J1 (USB通讯)

1	VDD/SV	定义
2	D-	
3	D+	
4	GND	
5	GND	

AC-C1271-43.0 Drawing

DESIGN	DATE	DATE	SHEET	UNIT	SCALE	1st ANGLE PROJECTION
John		2017.12.19	1 of 1	mm	1:1	